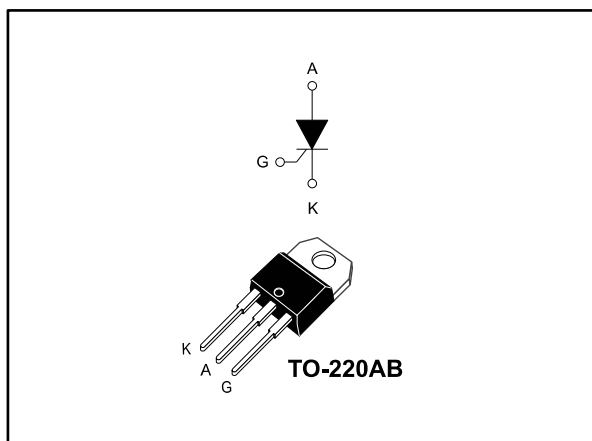


High temperature 40 A SCRs

Datasheet - production data



Features

- High junction temperature: $T_j = 150\text{ }^{\circ}\text{C}$
- High noise immunity $dV/dt = 500\text{ V}/\mu\text{s}$ up to $150\text{ }^{\circ}\text{C}$
- Gate triggering current $I_{GT} = 15\text{ mA}$
- Peak off-state voltage $600\text{ V } V_{DRM}/V_{RRM}$
- High turn on current rise $dI/dt = 100\text{ A}/\mu\text{s}$
- ECOPACK[®]2 compliant component
- Insulated package TO-220AB:
 - Insulated voltage: 2500 V_{RMS}
- Complies with UL 1557 (File ref : E81734)

Applications

- Motorbike voltage regulator circuits
- Inrush current limiting circuit
- Motor control circuits and starters
- Solid state relays

Description

Thanks to its junction temperature T_j up to $150\text{ }^{\circ}\text{C}$, the device offers high thermal performances operation up to 40 A . It is fully tab insulated thanks to the ceramic inside the TO-220AB package and allows a back to back configuration.

Its trade-off noise immunity ($dV/dt = 500\text{ V}/\mu\text{s}$) versus its gate triggering current ($I_{GT} = 15\text{ mA}$) and its turn-on current rise ($dI/dt = 100\text{ A}/\mu\text{s}$) allows to design robust and compact control circuit for voltage regulator in motorbikes and industrial drives, overvoltage crowbar protection, motor control circuits in power tools and kitchen aids, inrush current limiting circuits.

Table 1: Device summary

Order code	Package	V_{DRM}/V_{RRM}	I_{GT}
TN4015H-6I	TO-220AB ins.	600 V	15 mA

1 Characteristics

Table 2: Absolute maximum ratings (limiting values), $T_J = 25\text{ }^{\circ}\text{C}$ unless otherwise specified

Symbol	Parameter		Value	Unit
$I_{T(RMS)}$	RMS on-state current (180 ° conduction angle)		$T_c = 82\text{ }^{\circ}\text{C}$ 40	A
$I_{T(AV)}$	Average on-state current (180 ° conduction angle)		$T_c = 83\text{ }^{\circ}\text{C}$ 25	A
			$T_c = 94\text{ }^{\circ}\text{C}$ 22	
			$T_c = 101\text{ }^{\circ}\text{C}$ 20	
I_{TSM}	Non repetitive surge peak on-state current		$t_p = 8.3\text{ ms}$ 394	A
			$t_p = 10\text{ ms}$ 360	
I^2t	I^2t value for fusing		$t_p = 10\text{ ms}$ 648	A^2s
di/dt	Critical rate of rise of on-state current $I_G = 2 \times I_{GT}$, $t_r \leq 100\text{ ns}$		$f = 60\text{ Hz}$ 100	$\text{A}/\mu\text{s}$
V_{DRM}/V_{RRM}	Repetitive peak off-state voltage		$T_J = 150\text{ }^{\circ}\text{C}$ 600	V
V_{DSM}/V_{RSM}	Non repetitive surge peak off-state voltage		$t_p = 10\text{ ms}$ $V_{DRM}/V_{RRM} + 100$	V
I_{GM}	Peak gate current	$t_p = 20\text{ }\mu\text{s}$	$T_J = 150\text{ }^{\circ}\text{C}$ 4	A
$P_{G(AV)}$	Average gate power dissipation		$T_J = 150\text{ }^{\circ}\text{C}$ 1	W
V_{RGM}	Maximum peak reverse gate voltage		5	V
T_{stg}	Storage junction temperature range		-40 to +150	$^{\circ}\text{C}$
T_J	Maximum operating junction temperature		-40 to +150	$^{\circ}\text{C}$
T_L	Maximum lead temperature soldering during 10 s		260	$^{\circ}\text{C}$

Table 3: Electrical characteristics ($T_J = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)

Symbol	Test Conditions		Value	Unit	
I _{GT}	V _D = 12 V, R _L = 33 Ω		Max.	15	mA
V _{GT}			Max.	1.3	V
V _{GD}	V _D = V _{DRM} , R _L = 3.3 kΩ	T _j = 150 °C	Min.	0.15	V
I _H	I _T = 500 mA, gate open		Max.	60	mA
I _L	I _G = 1.2 x I _{GT}		Max.	80	mA
dV/dt	V _D = 402 V, gate open	T _j = 150 °C	Min.	500	V/μs
t _{gt}	I _T = 80 A, V _D = 600 V, I _G = 100 mA, (dI _G /dt) max = 0.2 A/μs		Typ.	1.9	μs
t _q	V _D = 402 V, I _T = 40 A, V _R = 25 V, dV _D /dt = 50 V/μs, (dI _G /dt) max = 30 A/μs	T _j = 150 °C	Typ.	85	μs

Table 4: Static characteristics

Symbol	Test conditions			Value	Unit
V_{TM}	$I_{TM} = 80\text{ A}$, $t_p = 380\text{ }\mu\text{s}$	$T_j = 25\text{ }^{\circ}\text{C}$	Max.	1.6	V
V_{TO}	Threshold voltage	$T_j = 150\text{ }^{\circ}\text{C}$	Max.	0.85	
R_D	Dynamic resistance	$T_j = 150\text{ }^{\circ}\text{C}$	Max.	10	m Ω
I_{DRM} , I_{RRM}	$V_D = V_{DRM} = V_{RRM}$	$T_j = 25\text{ }^{\circ}\text{C}$	Max.	10	μA
		$T_j = 150\text{ }^{\circ}\text{C}$		6	mA

Table 5: Thermal parameters

Symbol	Parameter		Value	Unit
$R_{th(j-c)}$	Junction to case (DC)	Max.	1.8	$^{\circ}\text{C/W}$
$R_{th(j-a)}$	Junction to ambient (DC)	Typ.	60	

1.1 Characteristics (curves)

Figure 1: Maximum average power dissipation versus average on-state current

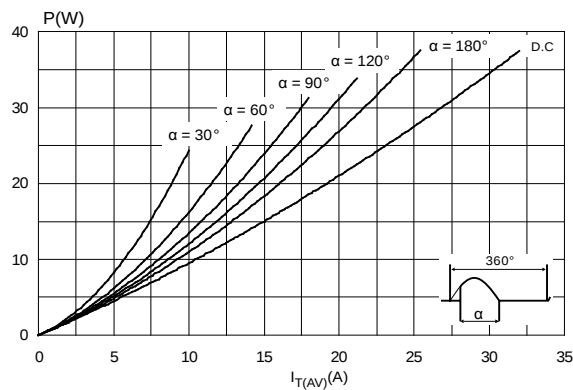


Figure 2: Average and DC on-state current versus case temperature

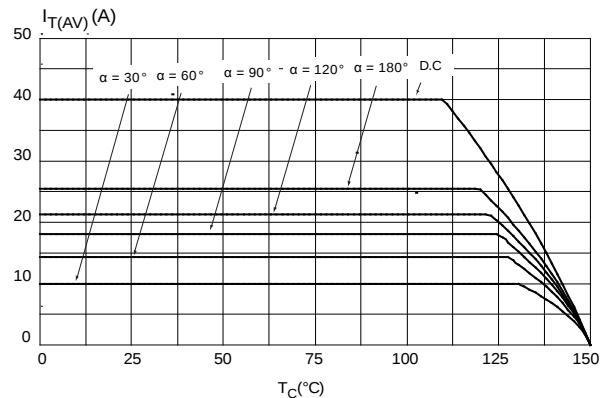


Figure 3: Average and D.C. on state current versus ambient temperature

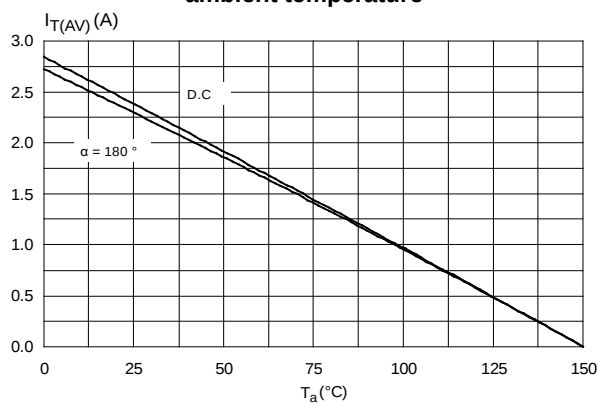


Figure 4: Relative variation of thermal impedance versus pulse duration

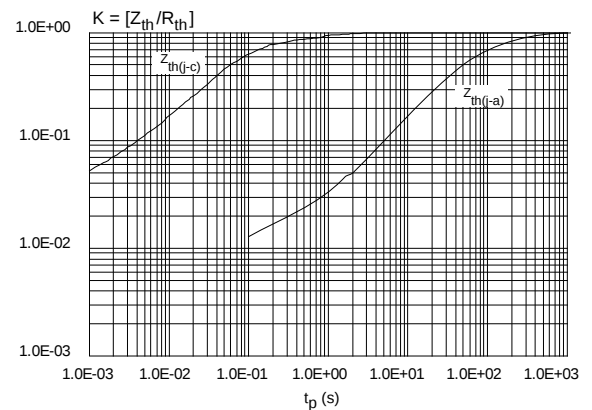


Figure 5: Relative variation of gate trigger current and gate voltage versus junction temperature (typical values)

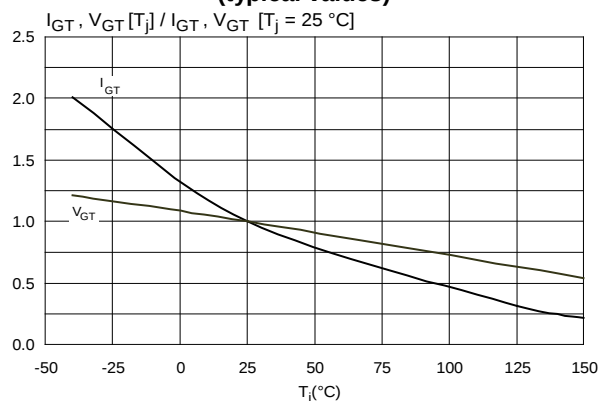


Figure 6: Relative variation of holding and latching current versus junction temperature (typical values)

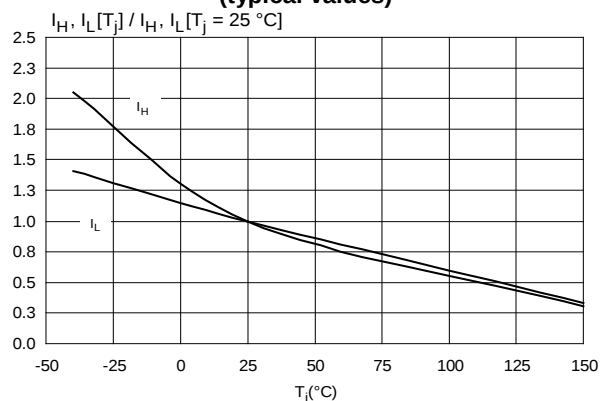


Figure 7: Relative variation of static dV/dt immunity versus junction temperature (typical values)

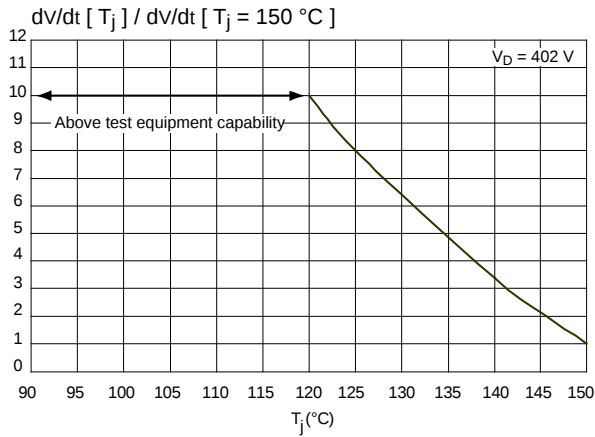


Figure 8: Surge peak on-state current versus number of cycles

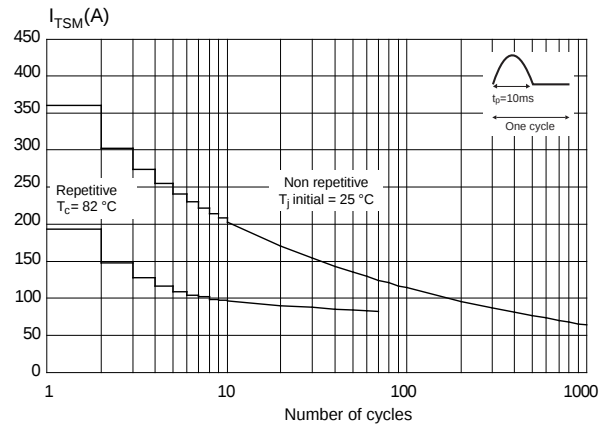


Figure 9: Non repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 10\text{ ms}$

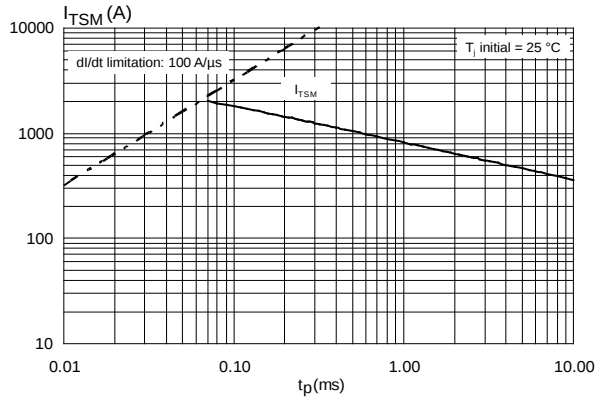


Figure 10: On-state characteristics (maximum values)

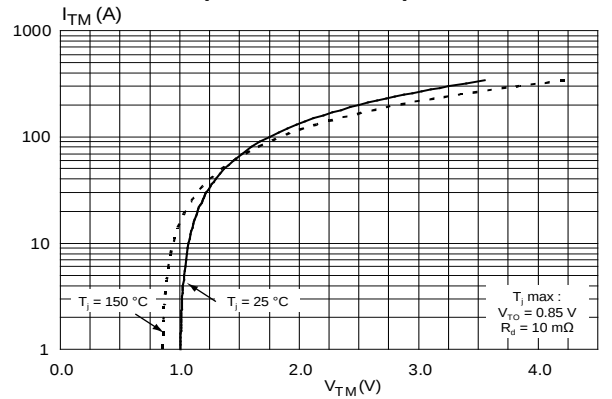
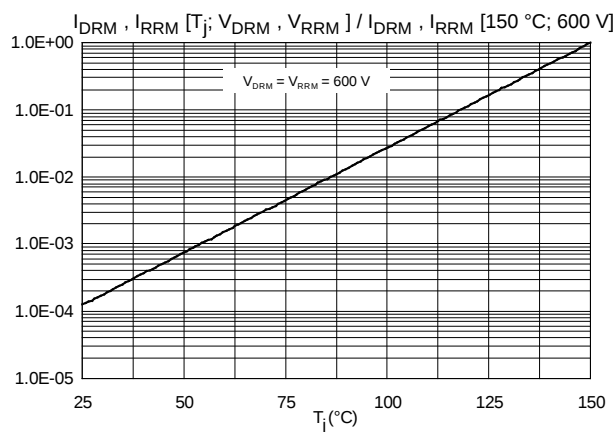


Figure 11: Relative variation of leakage current versus junction temperature



2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

- Epoxy meets UL94, V0
- Lead-free, halogen-free package

2.1 TO-220AB insulated package information

Figure 12: TO-220AB insulated package outline

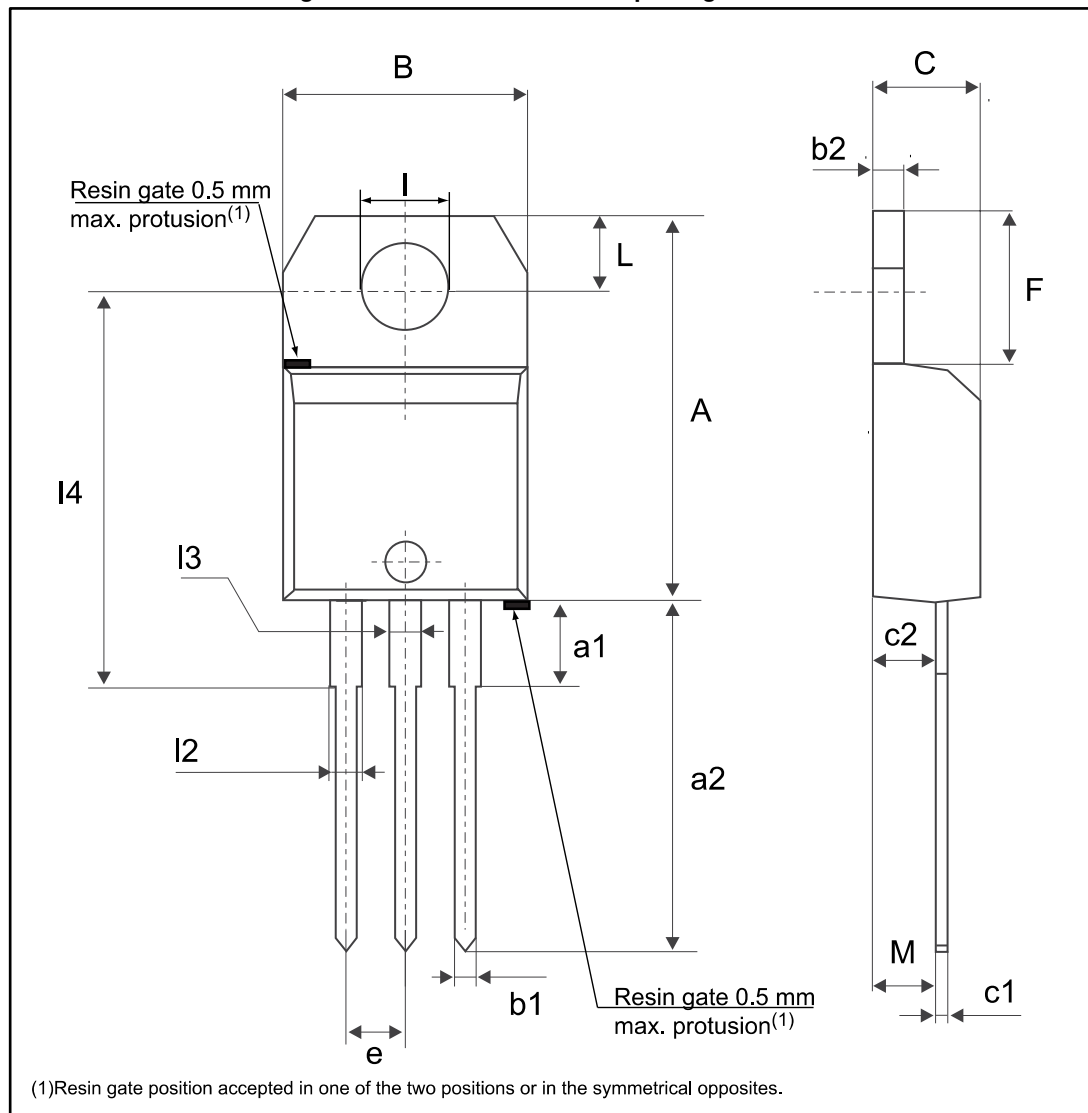


Table 6: TO-220AB insulated package mechanical data

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	15.20		15.90	0.5984		0.6260
a1		3.75			0.1476	
a2	13.00		14.00	0.5118		0.5512
B	10.00		10.4	0.3937		0.4094
b1	0.61		0.88	0.0240		0.0346
b2	1.23		1.32	0.0484		0.0520
C	4.40		4.60	0.1732		0.1811
c1	0.49		0.70	0.0193		0.0276
c2	2.40		2.72	0.0945		0.1071
e	2.40		2.70	0.0945		0.1063
F	6.20		6.60	0.2441		0.2598
ØI	3.73		3.88	0.1469		0.1528
I4	15.80	16.40	16.8	0.6220	0.6457	0.6614
L	2.65		2.95	0.1043		0.1161
I2	1.14		1.70	0.0449		0.0669
I3	1.14		1.70	0.0449		0.0669
M		2.60			0.1024	

3 Ordering information

Figure 13: Ordering information scheme

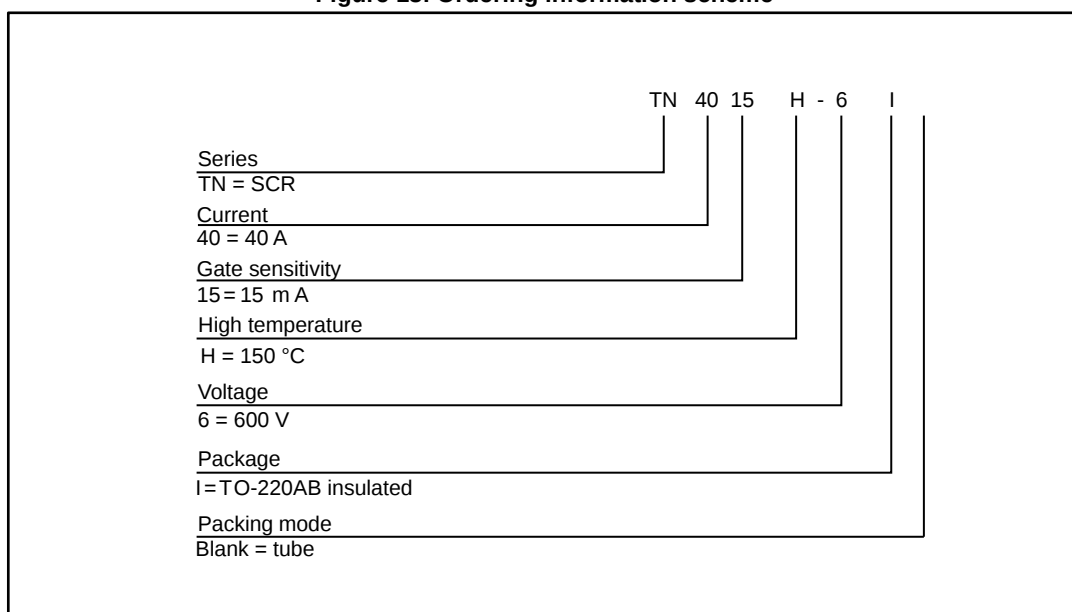


Table 7: Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
TN4015H-6I	TN4015H6I	TO-220AB Ins.	2.3 g	50	Tube

4 Revision history

Table 8: Document revision history

Date	Revision	Changes
05-Oct-2016	1	Initial release.
25-Nov-2016	2	Updated cover image.

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